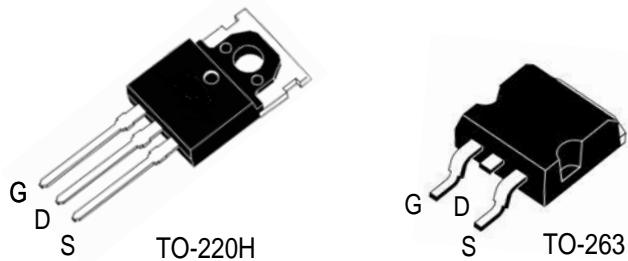




## POWER MOSFET

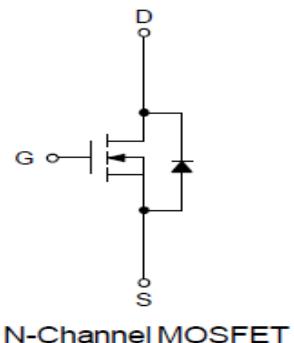
### Features

- 68V,80A N-Channel MOSFET
- $R_{DS(on)}(typ.)=6.5\text{m}\Omega$  @  $V_{GS}=10\text{V}$
- High ruggedness
- Fast switching
- 100% avalanche tested
- Exceptional dv/dt capability



### Applications

- Switching application



N-Channel MOSFET

### Absolute Maximum Ratings

Symbol	Parameter	Value	Units
$V_{DSS}$	Drain-Source Voltage	68	V
$V_{GS}$	Gate-Source Voltage	+25	V
$I_D$	Continuous Drain Current( $T_C=25^\circ\text{C}$ )	70	A
$I_{DM}$	Pulsed Drain Current(Note 1)	240	A
EAS	Single Pulsed Avalanche Energy(Note 2)	256	mJ
$P_D$	Maximum Power Dissipation ( $T_C=25^\circ\text{C}$ )	65	W
	Maximum Power Dissipation ( $T_C=100^\circ\text{C}$ )	32	W
$T_J$	Operating Junction Temperature Range	-55 to +175	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range	-55 to +175	$^\circ\text{C}$

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature
2. Starting  $T_J=25^\circ\text{C}$ ,  $L=1.0\text{mH}$ ,  $R_G=50\ \Omega$ ,  $I_D=37\text{A}$ ,  $V_{GS}=10\text{V}$



## Thermal data

Symbol	Parameter	Max.	Units
$R_{th\ J-C}$	Thermal Resistance, Junction to case	2.2	°C / W

## Electrical Characteristics ( $T_C=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	68			V
$I_{DSSS}$	Drain-Source Leakage Current	$V_{DS}=68V, V_{GS}=0V$			1	$\mu A$
$I_{GSS}$	Gate Leakage Current, Forward	$V_{GS}=25V, V_{DS}=0V$			100	nA
	Gate Leakage Current, Reverse	$V_{GS}=-25V, V_{DS}=0V$			-100	nA
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS}=V_{DS}, I_D=250\mu A$	2	3	4	V
$R_{DS(on)}$	Collector-Emitter Saturation Voltage	$V_{GS}=10V, I_D=40A$		6.5	8	$m\Omega$
$g_{fs}$	Forward Transconductance	$V_{DS}=15V, I_D=30A$		28		S
$Q_g$	Total Gate Charge	$V_{DD}=68V$ $V_{GS}=10V$ $I_D=40A$		76		nC
$Q_{gs}$	Gate-Source Charge			17		nC
$Q_{gd}$	Gate-Drain Charge			24		nC
$t_{d(on)}$	Turn-on Delay Time	$V_{DD}=35V$ $V_{GS}=10V$ $I_D=25A$ $R_G=3.5\Omega$	-	37	-	ns
$t_r$	Turn-on Rise Time		-	35	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	110	-	ns
$t_f$	Turn-off Fall Time		-	77	-	ns
$C_{iss}$	Input Capacitance	$V_{DS}=30V$ $V_{GS}=0V$ $f = 1MHz$	-	3250	-	pF
$C_{oss}$	Output Capacitance		-	580	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	165	-	pF
$R_{Gint}$	Integrated gate resistor			1.5		$\Omega$

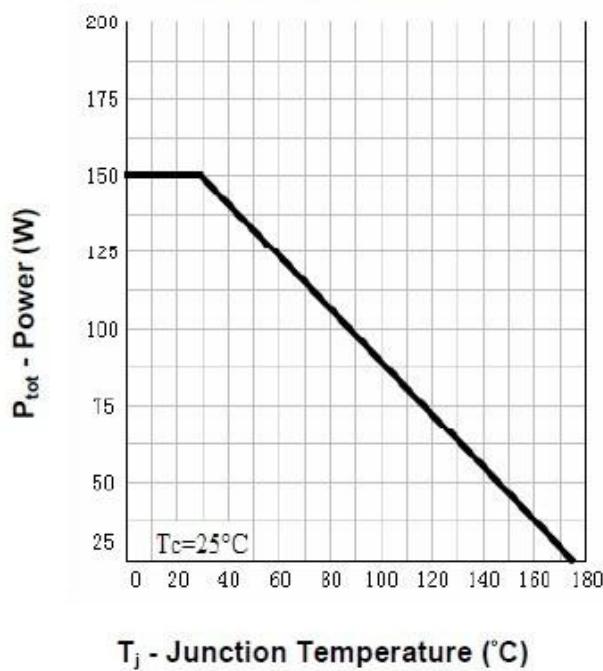
## Source-Drain Ratings and Characteristics ( $T_C=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V_{SD}$	Forward On Voltage	$V_{GS}=0V, I_S=20A$	-		1.2	V
$I_S$	Continuous Diode Forward Current				85	A
$t_{rr}$	Reverse Recovery Time	$V_{DD}=25V, I_S=40A$ $dI_F/dt=100A/us$	-	42		ns
$Q_{rr}$	Reverse Recovery Charge		-	70		nC

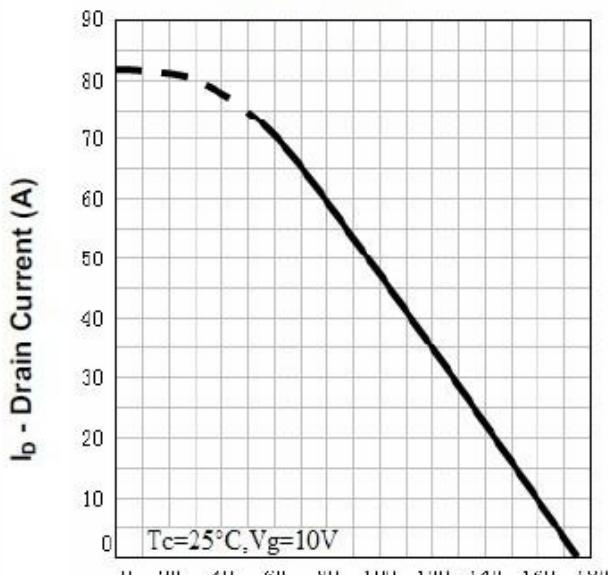


## Typical Characteristics

Power Dissipation



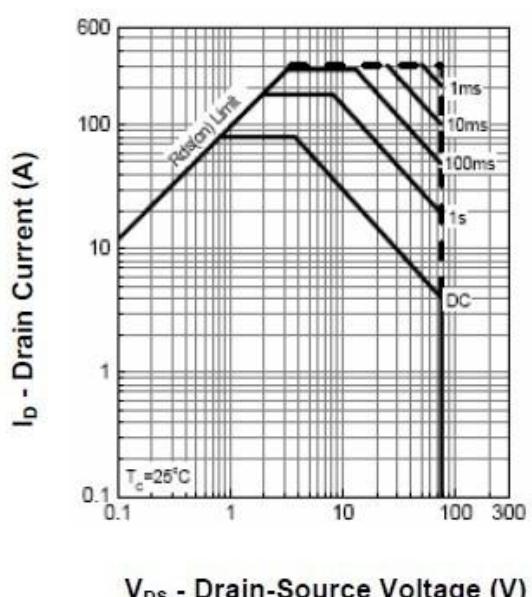
Drain Current



$T_j$  - Junction Temperature (°C)

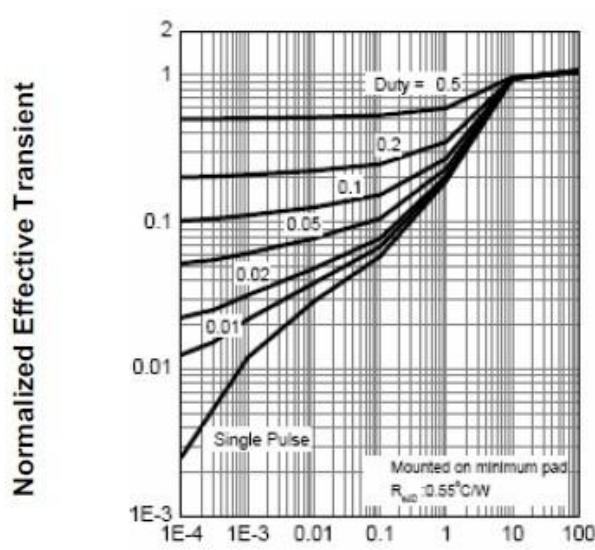
$T_j$  - Junction Temperature (°C)

Safe Operation Area



$V_{DS}$  - Drain-Source Voltage (V)

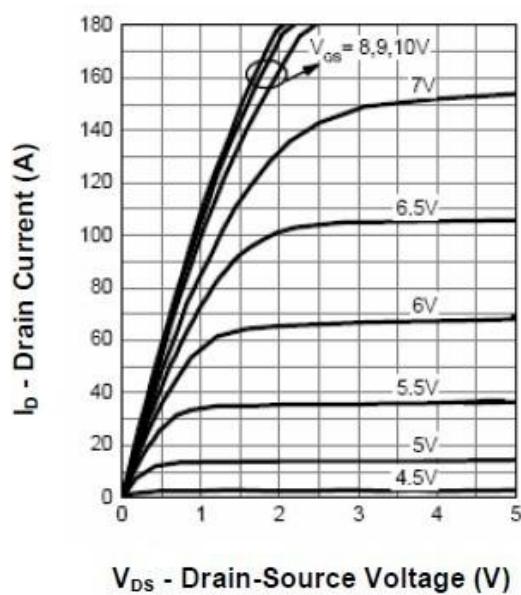
Thermal Transient Impedance



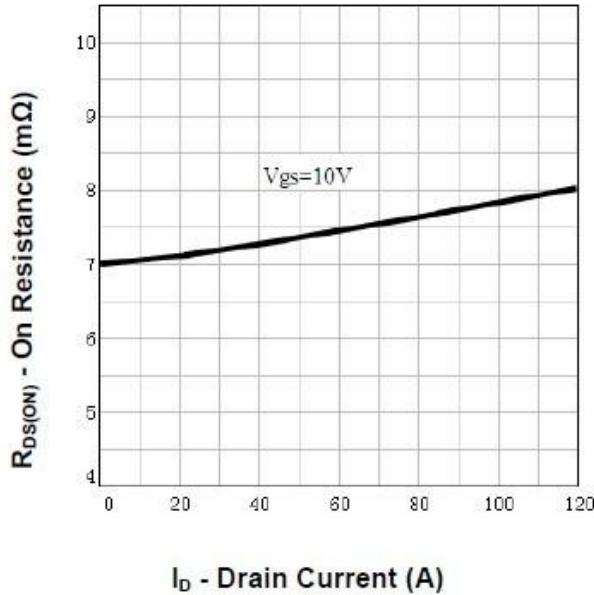
Square Wave Pulse Duration (sec)

## Typical Characteristics

Output Characteristics



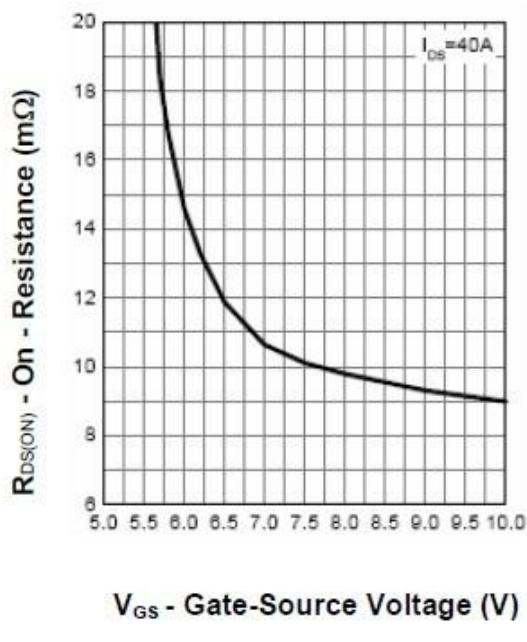
Drain-Source On Resistance



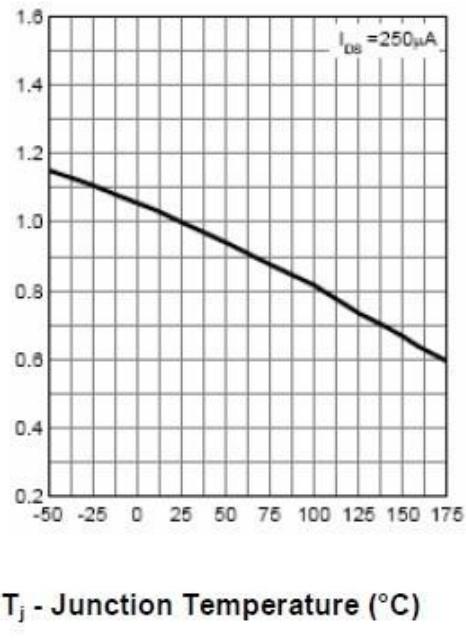
Drain-Source On Resistance

$I_D$  - Drain Current (A)

Gate Threshold Voltage



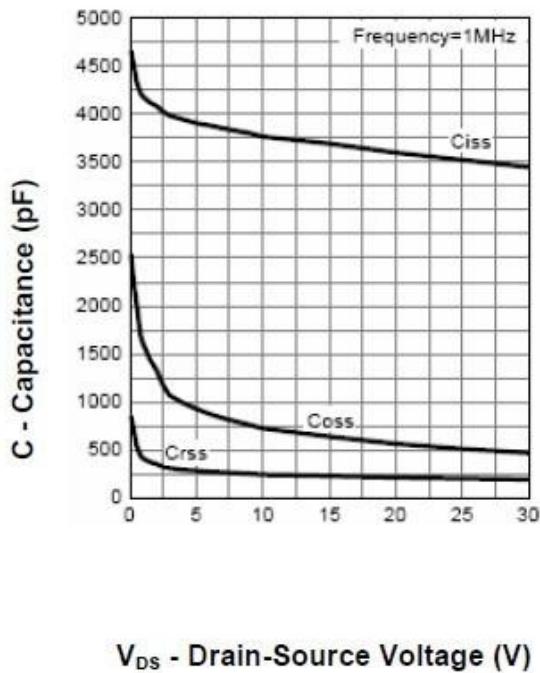
Normalized Threshold Voltage



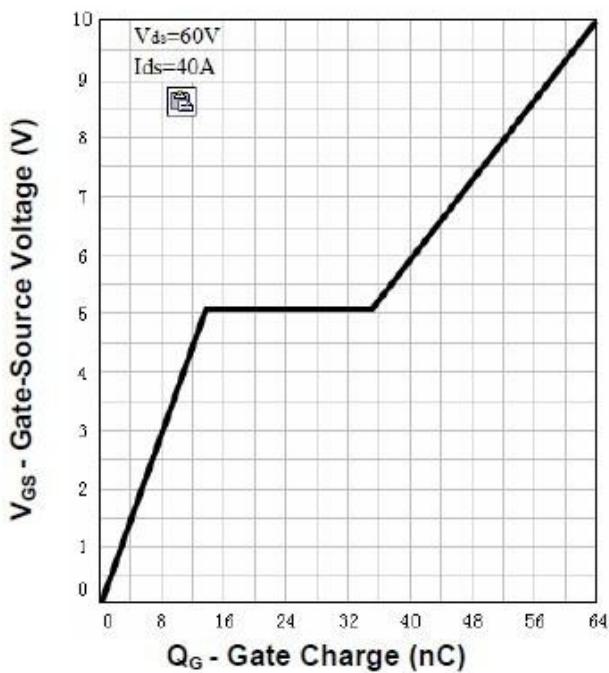
$V_{GS}$  - Gate-Source Voltage (V)

$T_j$  - Junction Temperature (°C)

**Capacitance**

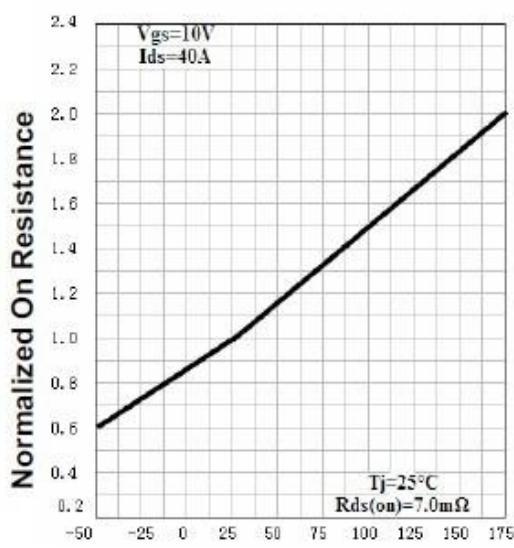


**Gate Charge**

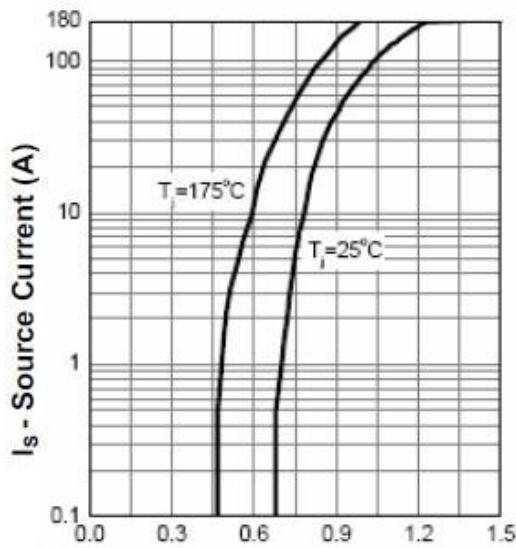


## Typical Characteristics

**Drain-Source On Resistance**



**Source-Drain Diode Forward**

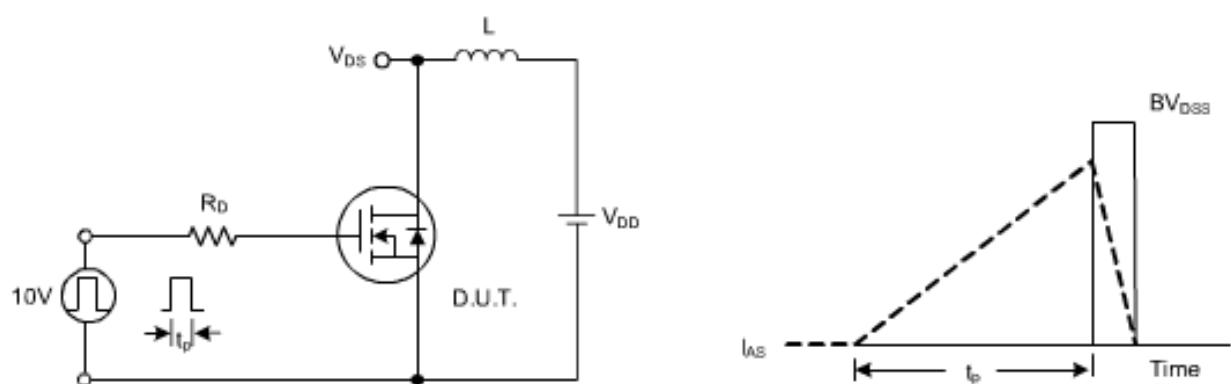


$T_j$  - Junction Temperature ( $^{\circ}$ C)

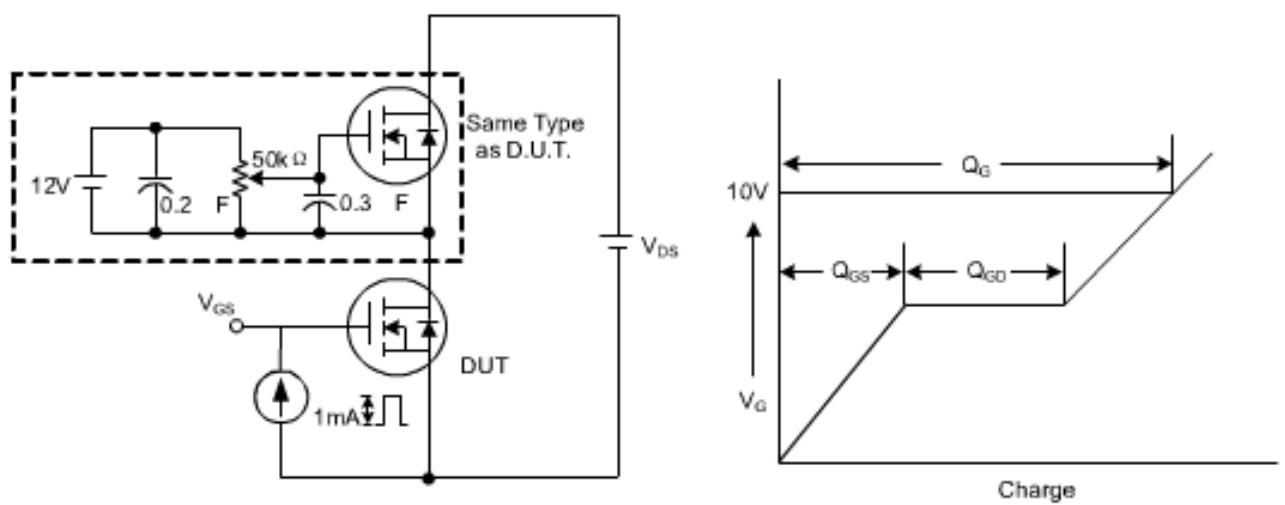
$V_{SD}$  - Source-Drain Voltage (V)

## Test Circuits

### Avalanche test circuits and waveforms

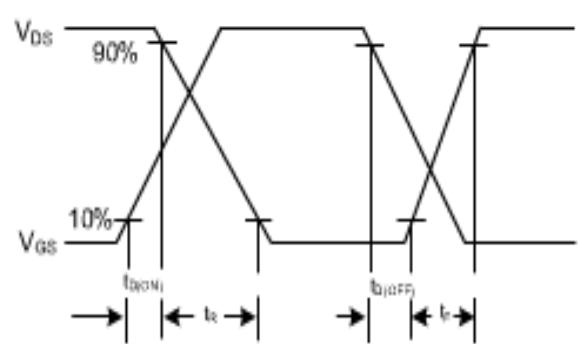
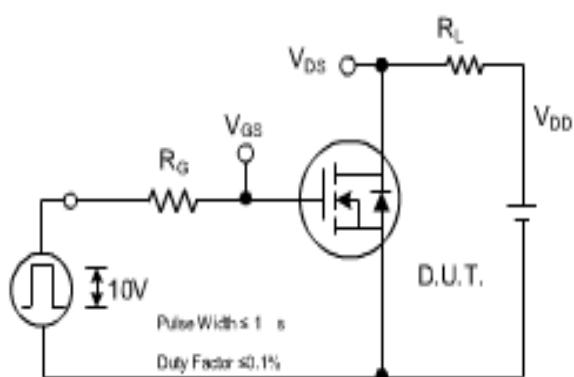


### Gate charge test circuits and waveforms





## Switching time test circuits and waveforms



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